

P3CD100065P

650V/100A SiC Power Schottky Barrier Diode Product



Features

- Positive temperature coefficient for easy parallel use
- Switching characteristics that are not affected by temperature
- Maximum operating temperature 175 °C
- Zero reverse recovery current
- Zero forward recovery voltage

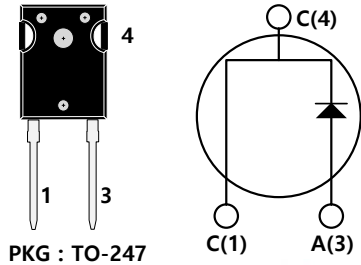
Key Characteristics		
V_{RRM}	650	V
I_F	-	A
Q_C	385	nC

Benefits

- Unipolar device
- Greatly reduce switching losses
- No thermal crash in parallel devices
- Reduce system dependence on heat sinks

Applications

- Switch Mode Power Supply (SMPS), Power Factor Correction (PFC)
- Motor drive, photovoltaic inverter, uninterruptible power supply, Wind turbines, train traction systems, electric vehicles.



PKG : TO-247



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Test Condition	Value	Unit
V_{RRM}	Repetitive Peak Reverse Voltage		650	V
V_{RSM}	Surge Peak Reverse Voltage		650	V
V_{DC}	DC Blocking Voltage		650	V
I_F	Continuous Forward Current	-	-	A
		-	-	A
		-	-	A
I_{FRM}	Repetitive Peak Forward Surge Current	$T_C=25^\circ\text{C}$, $t_p=10\text{ms}$, Half Sine Wave, $D=0.3$	-	A
I_{FSM}	Non-repetitive Peak Forward Surge Current	$T_C=25^\circ\text{C}$, $t_p=10\text{ms}$, Half Sine Wave	-	A
P_{TOT}	Power Dissipation	$T_C=25^\circ\text{C}$	238	W
		$T_C=110^\circ\text{C}$	103	
T_j	Operating Junction		-55 to 175	$^\circ\text{C}$
T_{stg}	Storage Temperature		-55 to 175	$^\circ\text{C}$



Thermal Characteristics

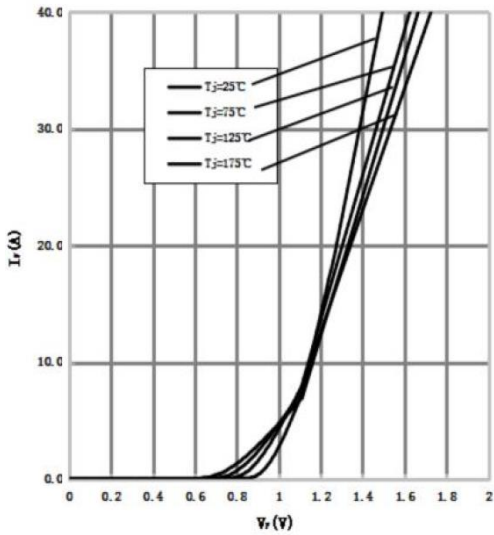
Symbol	Parameter	Test Condition	Value	Unit
			Typ.	
R_{thJc}	Thermal resistance from junction to case		0.63	°C/W

Electrical Characteristics, no specific temperature, junction temperature $T_j=25^\circ\text{C}$

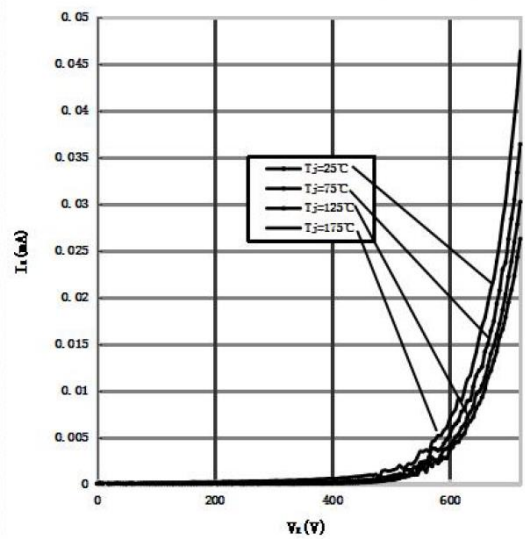
Symbol	Parameter	Test Condition	Numerical		Unit
			Typ.	Max.	
V_F	Forward Voltage	$I_F=40\text{A}, T_j=25^\circ\text{C}$	1.5	1.7	V
		$I_F=40\text{A}, T_j=175^\circ\text{C}$	1.7	2	
I_R	Reverse Current	$V_R=650\text{V}, T_j=25^\circ\text{C}$	10	50	μA
		$V_R=650\text{V}, T_j=175^\circ\text{C}$	20	100	
Q_C	Total capacitive Charge	$V_R=400\text{V}, T_j=150^\circ\text{C}$ $Q_C = \int_0^{V_R} C(V)dV$	385	-	nC
C	Total Capacitance	$V_R=0\text{V}, T_j=25^\circ\text{C}, f=1\text{MHZ}$	13500	14000	pF
		$V_R=200\text{V}, T_j=25^\circ\text{C}, f=1\text{MHZ}$	745	755	
		$V_R=400\text{V}, T_j=25^\circ\text{C}, f=1\text{MHZ}$	730	740	

Performance Graphs

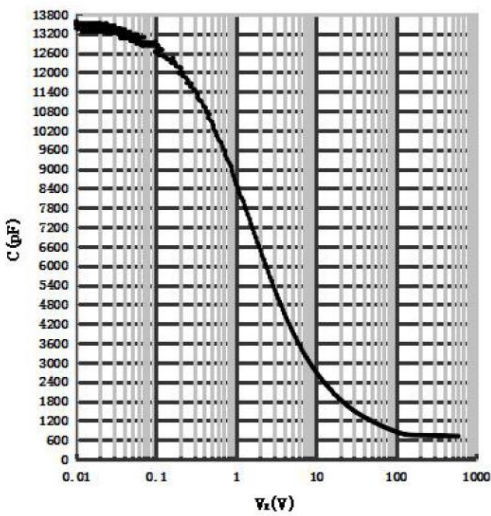
1) Forward IV characteristics as a function of T_j



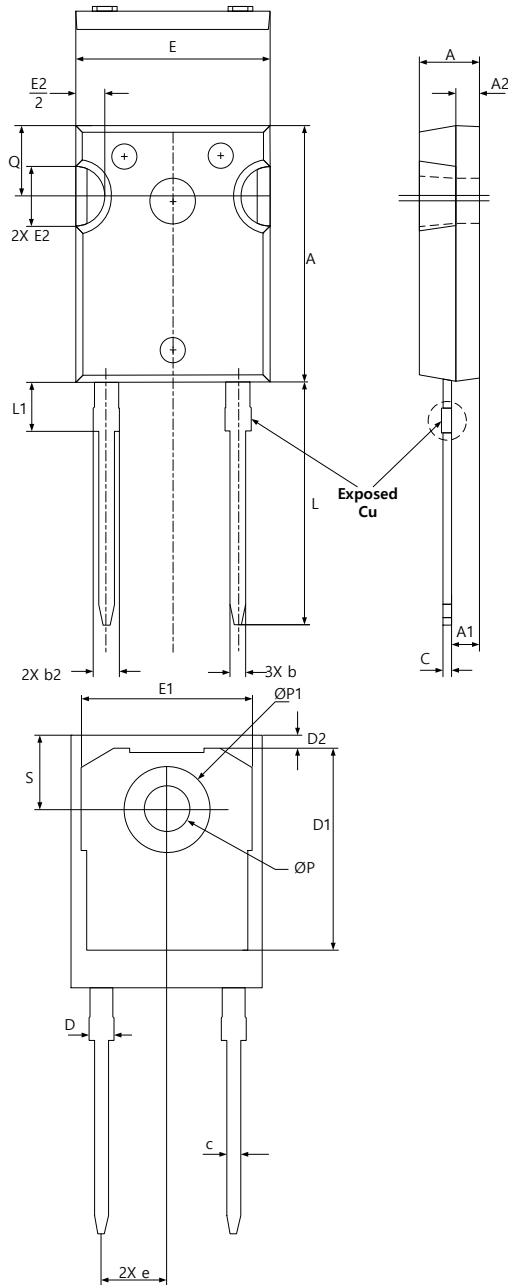
2) Reverse IV characteristics as a function of T_j



3) Capacitance VS. reverse voltage



Package Outline



SYMBOL	DIMENSIONS			NOTES
	MIN	NOM	MAX	
A	4.83	5.02	5.21	
A1	2.29	2.41	2.55	
A2	1.50	2.00	2.49	
B	1.12	1.20	1.33	
B1	1.12	1.20	1.28	
B2	1.91	2.00	2.39	6
B3	1.91	2.00	2.34	
C	0.55	0.60	0.69	6
C1	0.55	0.60	0.65	
D	20.80	20.95	21.10	4
D1	16.25	16.55	17.65	5
D2	0.51	1.19	1.35	
E	15.75	15.94	16.13	4
E1	13.46	14.02	14.16	5
E2	4.32	4.91	5.49	3
e	5.44BSC			
L	19.81	20.07	20.32	
L1	4.10	4.19	4.40	6
ØP	3.56	3.61	3.65	7
ØP1	7.19REF			
Q	5.39	5.79	6.20	
S	6.04	6.17	6.30	

Symbol	Parameter	Test Condition	Numerical		Unit
			Typ.	Max.	
M _d	Mounting torque	TO-247 M3 Screw 6-32 Screw	1/8.8	-	Nm/lbf.in.